

Dual Channel Voltage Detector

Features

- Two Independent Voltage Detectors in One Package
- Highly Accurate: ±2%
- Low Power Consumption: 2.0μA, Typ.
 Detect Voltage Range: 1.5V to 5.0V
- Operating Voltage: 1.5V to 10.0V
- Output Configuration: N-Channel Open-Drain
- Space-Saving 5-Pin SOT-23A Package

Typical Applications

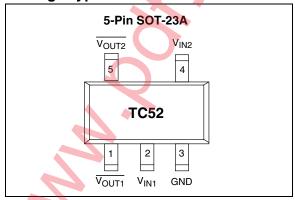
- Battery Life Monitors and Recharge Voltage Monitors
- · Memory Battery Backup Circuitry
- · Power-On Reset Circuits
- Power Failure Detection
- · Delay Circuitry

Device Selection Table

Part Number	Package	Temp. Range	
TC52-xxxxxxxxxx	5-Pin SOT-23A	-40°C to +85°C	

Other output voltages are available. Please contact Microchip Technology Inc. for details.

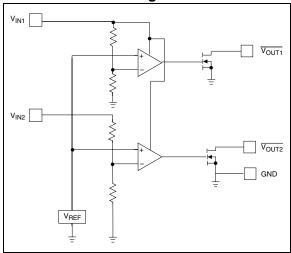
Package Type



General Description

The TC52 consists of two independent low power voltage detectors in a space-saving 5-pin SOT-23A package. Typical supply current consumption is only $2\mu A$ at an input voltage of 2V. The voltage detection threshold settings are factory-programmed and guaranteed to $\pm 2\%$ accuracy. Threshold settings over a range of 1.5V to 5.0V are available. The TC52 is available with open drain (NMOS) configurations. Small size, high precision, low supply current, and low installed cost makes the TC52 the ideal voltage detector for a wide variety of voltage monitoring applications.

Functional Block Diagram



ELECTRICAL 1.0 **CHARACTERISTICS**

Absolute Maximum Ratings*

Input Voltage+12V Output Current50mA Output Voltage..... V_{IN} + 0.3V to V_{SS} – 0.3V Power Dissipation 5-Pin SOT-23A100mW Operating Temperature Range.....-40°C to +85°C Storage Temperature Range-40°C to +125°C *Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions above those indicated in the operation sections of the specifications is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

TC52 ELECTRICAL SPECIFICATIONS

Electrical Characteristics: T _A = 25°C, unless otherwise specified. Note 1.						
Symbol	Parameter	Min	Тур	Max	Units	Test Conditions
V _{IN}	Operating Voltage	1.5	_	10.0	V	$V_{DF}(T) = 1.5 \text{ to } 5.0 \text{V}$
I _{SS}	Supply Current		1.35 1.50	3.90 4.50	μΑ	$V_{IN1} = 1.5V$ $V_{IN1} = 2.0V$
		_ _ _	1.95 2.40 3.00	5.10 5.70 6.30		$V_{IN1} = 3.0V$ $V_{IN1} = 4.0V$ $V_{IN1} = 5.0V$
I _{IN2}	Input Current V _{IN2}	_ _ _ _ _	0.45 0.50 0.65 0.80 1.00	1.30 1.50 1.70 1.90 2.10	μА	$V_{IN1} = 1.5V$ $V_{IN1} = 2.0V$ $V_{IN1} = 3.0V$ $V_{IN1} = 4.0V$ $V_{IN1} = 5.0V$
V _{DET1} -	Channel 1 Detect Voltage	V _{T1} x 0.98	V _{T1} ±0.5%	V _{T1} x 1.02	V	Note 2
V _{DET2} -	Channel 2 Detect Voltage	V _{T2} x 0.98	V _{T2} ±0.5%	V _{T2} x 1.02	V	Note 2
V _{HYS1}	Hysteresis Range 1	V _{DET1} - x 0.02	V _{DET1} - x 0.05	V _{DET1} - x 0.08	V	
V _{HYS2}	Hysteresis Range 2	V _{DET2} - x 0.02	V _{DET2} - x 0.05	V _{DET2} - x 0.08	V	
l _{OUT}	Output Current	0.3 3.0 5.0 6.0 7.0	2.2 7.7 10.1 11.5 13.0	11111	mA	$\begin{aligned} V_{OL} &= 0.5 \text{V}, \ V_{IN1} &= 1.0 \text{V} \\ V_{IN1} &= 2.0 \text{V} \\ V_{IN1} &= 3.0 \text{V} \\ V_{IN1} &= 4.0 \text{V} \\ V_{IN1} &= 5.0 \text{V} \end{aligned}$
ΔV_{DET} -/ $(\Delta T_{OPR} V_{DET}$ -)	Temperature Characteristics	_	±100		ppm/°C	-40°C ≤ T _{OPR} ≤ 85°C
t _{DLY}	Detection Time		_	0.2	msec	Time from $V_{IN} = V_{DET}$ - to $V_{OUT} = V_{OL}$

 Additional resistance between the V_{IN1} pin and the supply voltage may alter the electrical characteristics.
 V_{T1}, V_{T2} are the factory-programmed voltage detection thresholds. Note

2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

TABLE 2-1: PIN FUNCTION TABLE

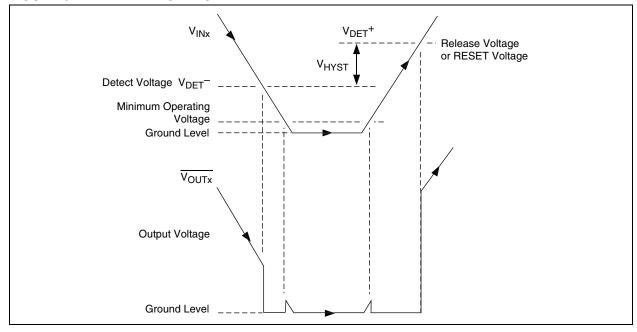
Pin No. (5-Pin SOT-23A)	Symbol	Description
1	V _{OUT1}	Detector #1 output.
2	V_{IN}	Supply voltage input, detect voltage 1.
3	GND	Ground terminal.
4	V _{IN2}	Detect voltage 2.
5	V_{OUT2}	Detector #2 output.

3.0 DETAILED DESCRIPTION

In normal steady-state operation and for either channel, when $V_{\text{IN}} > V_{\text{DET}}$ -, the output is high, see Figure 3-1. (In the case of the TC52N, this is an opendrain condition.) If and when the input falls below V_{DET} -, the output pulls down (Logic 0) to V_{SS} . Generally, V_{OUT} can pull down to within 0.5V of V_{SS} at rated output current and input voltages. (Also see Section 1.0, Electrical Characteristics).

The output, V_{OUT} , stays valid until the input voltage falls below the minimum operating voltage, V_{INMIN} , of 0.7V. Below this minimum operating voltage, the output is undefined. During power-up or anytime V_{IN} has fallen below V_{INMIN} , V_{OUT} will remain undefined until V_{IN} rises above V_{INMIN} , at which time the output becomes valid. V_{OUT} is maintained in its active low state while $V_{INMIN} < V_{IN} < V_{DET} + . (V_{DET} + V_{DET} + V_{HYST})$. If and when the input rises above $V_{DET} +$, the output will assume its inactive state (open-drain for TC52N).

FIGURE 3-1: TIMING DIAGRAM



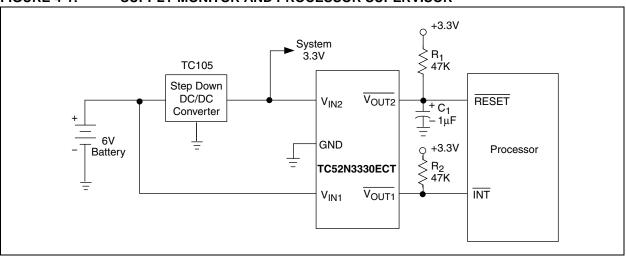
4.0 APPLICATIONS INFORMATION

Pin 2 (V_{IN1}) acts as both the input to Voltage Detector #1, as well as the power supply input for the chip. As such, always assign V_{IN1} to monitor voltages between 1.5V and 10V. Failure to do this will result in unreliable detector operation due to an out-of-tolerance supply voltage. In high noise environments, it may be necessary to install a small input bypass capacitor $(0.01\mu F$ to $0.1\mu F$) from V_{IN1} to ground to minimize onchip power supply noise.

4.1 Battery and Main Supply Monitor

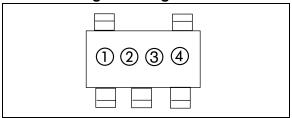
The circuit shown in Figure 4-1 provides both a processor supply monitor/reset function, as well as a low battery detect function. As shown, the TC52N3330ECT (N-Channel outputs) uses Detector 2 to monitor the system power supply rail. When the power supply is 10% below its nominal output voltage rating, the V_{OUT2} output is driven and held low. When the power supply voltage is above 3.0V nominal, V_{OUT2} is driven to an open circuit and the combination of R_1 and C_1 provides a reset time out delay. Detector 1 monitors the voltage on the main supply battery. A low battery condition is indicated when the battery voltage falls to 3.3V, at which time the main processor is interrupted to initiate a warning or system shutdown.

FIGURE 4-1: SUPPLY MONITOR AND PROCESSOR SUPERVISOR



5.0 **PACKAGING INFORMATION**

5.1 **Package Marking Information**



1 represents N-channel indication and integer part of output voltage

Symbol	Output		
<u>C</u>	CMOS		
<u>N</u>	Nch		

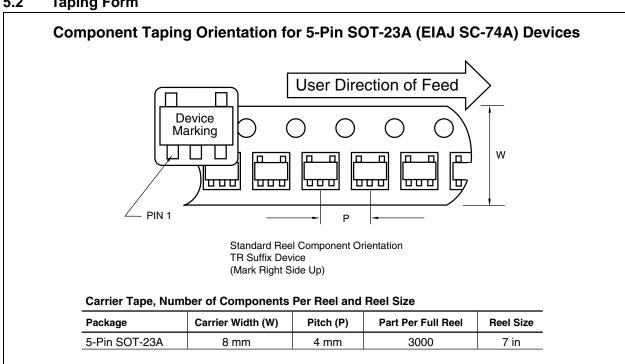
2 3 represents registration serial number

Symbol	Detect Voltage 1	Detect Voltage 2	
0P	4.5	2.7	

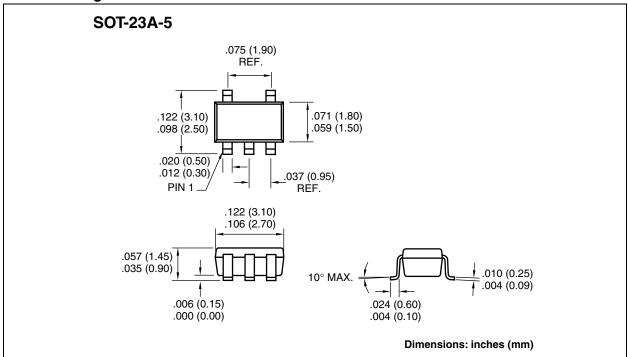
Note: Symbols for other custom voltages set prior to shipment.

4 represents assembly lot code

Taping Form 5.2

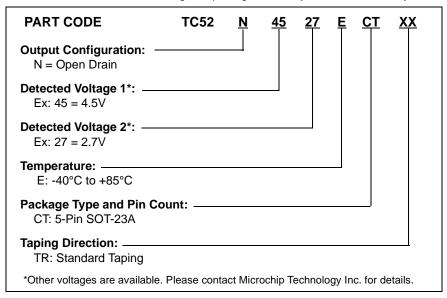


5.3 Package Dimensions



PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.



Sales and Support

Data Sheets

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

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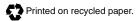
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WORLDWIDE SALES AND SERVICE

AMERICAS

Corporate Office

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support: 480-792-7627 Web Address: http://www.microchip.com

Rocky Mountain

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7966 Fax: 480-792-7456

Atlanta

500 Sugar Mill Road, Suite 200B Atlanta, GA 30350 Tel: 770-640-0034 Fax: 770-640-0307

Boston

2 Lan Drive, Suite 120 Westford, MA 01886 Tel: 978-692-3848 Fax: 978-692-3821

Chicago

333 Pierce Road, Suite 180 Itasca, IL 60143 Tel: 630-285-0071 Fax: 630-285-0075

Dallas

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Tel: 972-818-7423 Fax: 972-818-2924

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Kokomo

2767 S. Albright Road Kokomo, Indiana 46902 Tel: 765-864-8360 Fax: 765-864-8387

Los Angeles

18201 Von Karman, Suite 1090 Irvine, CA 92612

Tel: 949-263-1888 Fax: 949-263-1338

New York

150 Motor Parkway, Suite 202 Hauppauge, NY 11788 Tel: 631-273-5305 Fax: 631-273-5335

San Jose

Microchip Technology Inc. 2107 North First Street, Suite 590 San Jose, CA 95131 Tel: 408-436-7950 Fax: 408-436-7955

6285 Northam Drive, Suite 108 Mississauga, Ontario L4V 1X5, Canada Tel: 905-673-0699 Fax: 905-673-6509

ASIA/PACIFIC

Australia

Microchip Technology Australia Pty Ltd Suite 22, 41 Rawson Street Epping 2121, NSW

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Microchip Technology Consulting (Shanghai) Co., Ltd., Beijing Liaison Office Bei Hai Wan Tai Bldg.

No. 6 Chaoyangmen Beidajie Beijing, 100027, No. China

Tel: 86-10-85282100 Fax: 86-10-85282104

China - Chengdu

Microchip Technology Consulting (Shanghai) Co., Ltd., Chengdu Liaison Office Rm. 2401, 24th Floor, Ming Xing Financial Tower No. 88 TIDU Street Chengdu 610016, China Tel: 86-28-86766200 Fax: 86-28-86766599

China - Fuzhou

Microchip Technology Consulting (Shanghai) Co., Ltd., Fuzhou Liaison Office Unit 28F, World Trade Plaza No. 71 Wusi Road Fuzhou 350001, China Tel: 86-591-7503506 Fax: 86-591-7503521

China - Shanghai

Microchip Technology Consulting (Shanghai) Co., Ltd.

Room 701, Bldg. B Far East International Plaza No. 317 Xian Xia Road Shanghai, 200051

Tel: 86-21-6275-5700 Fax: 86-21-6275-5060

China - Shenzhen

Microchip Technology Consulting (Shanghai) Co., Ltd., Shenzhen Liaison Office Rm. 1315, 13/F, Shenzhen Kerry Centre, Renminnan Lu Shenzhen 518001, China Tel: 86-755-2350361 Fax: 86-755-2366086

China - Hong Kong SAR

Microchip Technology Hongkong Ltd. Unit 901-6, Tower 2, Metroplaza 223 Hing Fong Road Kwai Fong, N.T., Hong Kong Tel: 852-2401-1200 Fax: 852-2401-3431

India

Microchip Technology Inc. India Liaison Office Divyasree Chambers 1 Floor, Wing A (A3/A4) No. 11, O'Shaugnessey Road Bangalore, 560 025, India Tel: 91-80-2290061 Fax: 91-80-2290062

Japan

Microchip Technology Japan K.K. Benex S-1 6F 3-18-20, Shinyokohama Kohoku-Ku, Yokohama-shi Kanagawa, 222-0033, Japan Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea

Microchip Technology Korea 168-1, Youngbo Bldg. 3 Floor Samsung-Dong, Kangnam-Ku Seoul, Korea 135-882

Tel: 82-2-554-7200 Fax: 82-2-558-5934

Singapore

Microchip Technology Singapore Pte Ltd. 200 Middle Road #07-02 Prime Centre Singapore, 188980 Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan

Microchip Technology Taiwan 11F-3, No. 207 Tung Hua North Road Taipei, 105, Taiwan Tel: 886-2-2717-7175 Fax: 886-2-2545-0139

EUROPE

Denmark

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Germany

Microchip Technology GmbH Gustav-Heinemann Ring 125 D-81739 Munich, Germany Tel: 49-89-627-144 0 Fax: 49-89-627-144-44

Italy

Microchip Technology SRL Centro Direzionale Colleoni Palazzo Taurus 1 V. Le Colleoni 1 20041 Agrate Brianza Milan, Italy Tel: 39-039-65791-1 Fax: 39-039-6899883

United Kingdom

Microchip Ltd. 505 Eskdale Road Winnersh Triangle Wokingham Berkshire, England RG41 5TU Tel: 44 118 921 5869 Fax: 44-118 921-5820

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